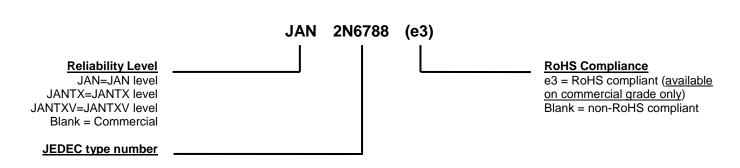


## **MECHANICAL and PACKAGING**

- CASE: Hermetically sealed, kovar base, nickel cap.
- TERMINALS: Tin/lead solder dip nickel plate or RoHS compliant pure tin plate (commercial grade only).
- MARKING: Part number, date code, manufacturer's ID.
- WEIGHT: Approximately 1.064 grams.
- See <u>Package Dimensions</u> on last page.

### **PART NOMENCLATURE**



	SYMBOLS & DEFINITIONS					
Symbol	Definition					
$I_{D}$	Drain current.					
I <sub>F</sub>	Forward current.					
Tc	Case temperature.					
$V_{DD}$	Drain supply voltage.					
$V_{DS}$	Drain to source voltage.					
$V_{GS}$	Gate to source voltage.					



# **ELECTRICAL CHARACTERISTICS** @ T<sub>A</sub> = +25 °C, unless otherwise noted

Parameters / Test Conditions		Symbol	Min.	Max.	Unit
OFF CHARACTERTICS					
Drain-Source Breakdown Voltage V <sub>GS</sub> = 0 V, I <sub>D</sub> = 1 mA	2N6788 2N6790	$V_{(BR)DSS}$	100 200		V
Gate-Source Voltage (Threshold) $V_{DS} \ge V_{GS}, I_D = 0.25 \text{ mA}$ $V_{DS} \ge V_{GS}, I_D = 0.25 \text{ mA}, T_j = +125 ^{\circ}\text{C}$ $V_{DS} \ge V_{GS}, I_D = 0.25 \text{ mA}, T_j = -55 ^{\circ}\text{C}$		V <sub>GS(th)1</sub> V <sub>GS(th)2</sub> V <sub>GS(th)3</sub>	2.0 1.0	4.0 5.0	V
Gate Current $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$ $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}, T_j = +125 °C$		I <sub>GSS1</sub>		±100 ±200	nA

Parameters / Test Conditions		Symbol	Min.	Max.	Unit
ON CHARACTERISTICS				<u>I</u>	
Drain Current $V_{GS} = 0V$ , $V_{DS} = 80 V$ $V_{GS} = 0V$ , $V_{DS} = 160 V$	2N6788 2N6790	I <sub>DSS1</sub>		25	μΑ
Drain Current $V_{GS} = 0V$ , $V_{DS} = 80$ V, $T_j = +125$ °C $V_{GS} = 0V$ , $V_{DS} = 160$ V, $T_j = +125$ °C	2N6788 2N6790	I <sub>DSS2</sub>		0.25	mA
Static Drain-Source On-State Resistance $V_{GS} = 10 \text{ V}, I_D = 3.5 \text{ A pulsed}$ $V_{GS} = 10 \text{ V}, I_D = 2.25 \text{ A pulsed}$	2N6788 2N6790	r <sub>DS(on)1</sub>		0.30 0.80	Ω
Static Drain-Source On-State Resistance $V_{GS} = 10 \text{ V}, I_D = 6.0 \text{ A pulsed}$ $V_{GS} = 10 \text{ V}, I_D = 3.5 \text{ A pulsed}$	2N6788 2N6790	r <sub>DS(on)2</sub>		0.35 0.85	Ω
Static Drain-Source On-State Resistance $T_j = +125$ °C: $V_{GS} = 10$ V, $I_D = 3.5$ A pulsed $V_{GS} = 10$ V, $I_D = 2.25$ A pulsed	2N6788 2N6790	r <sub>DS(on)3</sub>		0.54 1.50	Ω
Diode Forward Voltage $V_{GS} = 0 \text{ V}, I_D = 6.0 \text{ A pulsed}$ $V_{GS} = 0 \text{ V}, I_D = 3.5 \text{ A pulsed}$	2N6788 2N6790	V <sub>SD</sub>		1.8 1.5	V



# **ELECTRICAL CHARACTERISTICS** @ T<sub>A</sub> = +25 °C, unless otherwise noted (continued)

## **DYNAMIC CHARACTERISTICS**

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Gate Charge:				
1 66 10 1, 18 010 1, 180 00 1	2N6788 2N6790 Q <sub>g(on)</sub>		18.0 14.3	nC
- 00 10 1,15 010 1,150 00 1	2N6788 2N6790 Q <sub>gs</sub>		4.0 3.0	nC
1 66 10 1, 15 010 1, 150 00 1	2N6788 2N6790 Q <sub>gd</sub>		9.0 9.0	nC

### **SWITCHING CHARACTERISTICS**

Parameters / Test Conditions		Symbol	Min.	Max.	Unit
Turn-on delay time $I_D = 6.0 \text{ A}, V_{GS} = 10 \text{ V}, R_G = 7.5 \Omega, V_{DD} = 35 \text{ V}$ $I_D = 3.5 \text{ A}, V_{GS} = 10 \text{ V}, R_G = 7.5 \Omega, V_{DD} = 74 \text{ V}$	2N6788 2N6790	t <sub>d(on)</sub>		40	ns
Rinse time $I_D = 6.0 \text{ A}, V_{GS} = 10 \text{ V}, R_G = 7.5 \Omega, V_{DD} = 35 \text{ V}$ $I_D = 3.5 \text{ A}, V_{GS} = 10 \text{ V}, R_G = 7.5 \Omega, V_{DD} = 74 \text{ V}$	2N6788 2N6790	t <sub>r</sub>		70 50	ns
Turn-off delay time $I_D = 6.0 \text{ A}, V_{GS} = 10 \text{ V}, R_G = 7.5 \Omega, V_{DD} = 35 \text{ V}$ $I_D = 3.5 \text{ A}, V_{GS} = 10 \text{ V}, R_G = 7.5 \Omega, V_{DD} = 74 \text{ V}$	2N6788 2N6790	$t_{d(off)}$		40 50	ns
Fall time $I_D = 6.0 \text{ A}, \ V_{GS} = 10 \text{ V}, \ R_G = 7.5 \ \Omega, \ V_{DD} = 35 \text{ V}$ $I_D = 3.5 \text{ A}, \ V_{GS} = 10 \text{ V}, \ R_G = 7.5 \ \Omega, \ V_{DD} = 74 \text{ V}$	2N6788 2N6790	t <sub>f</sub>		70 50	ns
Diode Reverse Recovery Time di/dt = 100 A/ $\mu$ s, $V_{DD} \le 50$ V, $I_F = 6.0$ A di/dt = 100 A/ $\mu$ s, $V_{DD} \le 50$ V, $I_F = 3.5$ A	2N6788 2N6790	t <sub>rr</sub>		240 400	ns



### **GRAPHS**

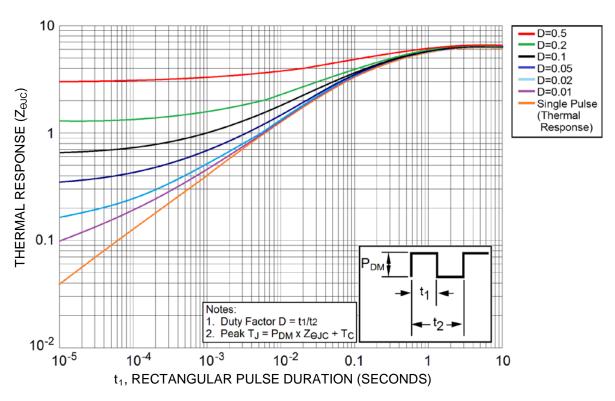
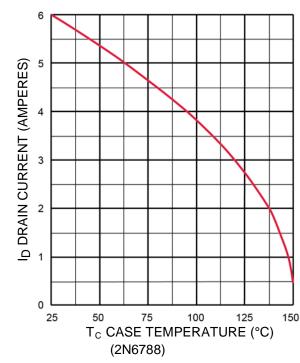


Figure 1
Thermal Impedance Curves



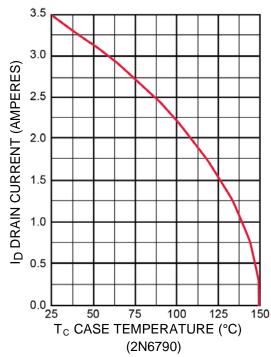
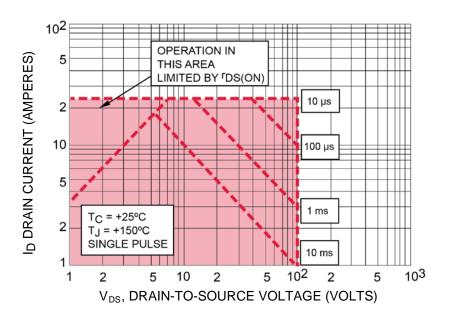


Figure 2

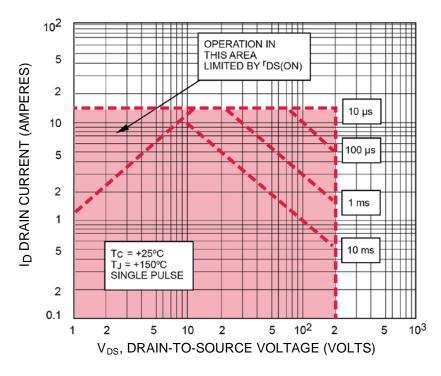
Maximum Drain Current vs. Case Temperature Graph



### **GRAPHS** (continued)



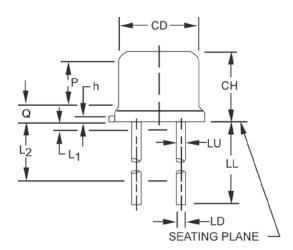
Maximum Safe Operating Area (2N6788)

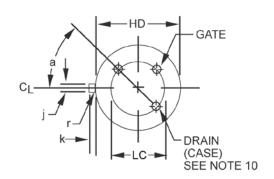


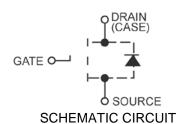
Maximum Safe Operating Area (2N6790)



## **PACKAGE DIMENSIONS**







Ltr	Inc	h	Millin	neters	Notes
	Min	Max	Min	Max	
CD	.305	.335	7.75	8.51	
СН	.160	.180	4.07	4.57	
HD	.335	.370	8.51	9.40	
h	.009	.041	0.23	1.04	
J	.028	.034	0.71	0.86	3
k	.029	.045	0.74	1.14	3, 4
LD	.016	.021	0.41	0.53	7, 8
LL	.500	.750	12.7	19.05	7, 8, 12
LS	.200	.200 TP		8 TP	6
LU	.016	.019	0.41	0.48	7, 8
L1		.050		1.27	7, 8
L2	.250		6.35		7, 8
Р	.100		2.54		
Q	_	.050		1.27	5
r		.010		0.25	10
α	45° TP		45	<sup>°</sup> TP	6

#### NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. Beyond r (radius) maximum, TL shall be held for a minimum length of .011 inch (0.28 mm).
- 4. Dimension TL measured from maximum HD.
- 5. Body contour optional within zone defined by HD, CD, and Q.
- 6. Leads at gauge plane .054 +.001 -.000 inch (1.37 +0.03 -0.00 mm) below seating plane shall be within .007 inch (0.18 mm) radius of true position (TP) at maximum material condition (MMC) relative to tab at MMC.
- 7. Dimension LU applies between L1 and L2. Dimension LD applies between L2 and LL minimum. Diameter is uncontrolled in L1 and beyond LL minimum.
- 8. All three leads.
- 9. The collector shall be internally connected to the case.
- 10. Dimension r (radius) applies to both inside corners of tab.
- 11. In accordance with ASME Y14.5M, diameters are equivalent to  $\Phi x$  symbology.
- 12. Lead 1 = source, lead 2 = gate, lead 3 = drain.